

Specifications

Parameter	Unit	Minimum	Typical	Maximum
Center Frequency	MHz	414	415	416
Insertion Loss(411~420MHz)	dB	-	2.2	3.5
1.5 dB Bandwidth	MHz	9	10.18	-
3 dB Bandwidth	MHz	-	11.51	-
Passband Variation(411~420MHz)	dB	-	0.2	1.5
Absolute Delay	usec	-	0.1	-
Group Delay Variation(411~420MHz)	nsec	-	45	-
S11(411~420MHz)	-	-	1.9	2
S22(411~420MHz)	-	-	1.85	2
Ultimate Rejection	DC~350MHz	dB	40	60
	550~1000MHz	dB	40	47
	1000~2000MHz	dB	30	33
Material Temperature coefficient	KHz/°C	-12.45		
Ambient Temperature	°C	25		
Package Size	SMD3.8*3.8			

Notes:


1. All specifications are based on the test circuit shown
2. In production, devices will be tested at room temperature to a guardbanded specification to ensure electrical compliance over temperature
3. Electrical margin has been built into the design to account for the variations due to temperature drift and manufacturing tolerances
4. This is the optimum impedance in order to achieve the performance show

Matching Configuration

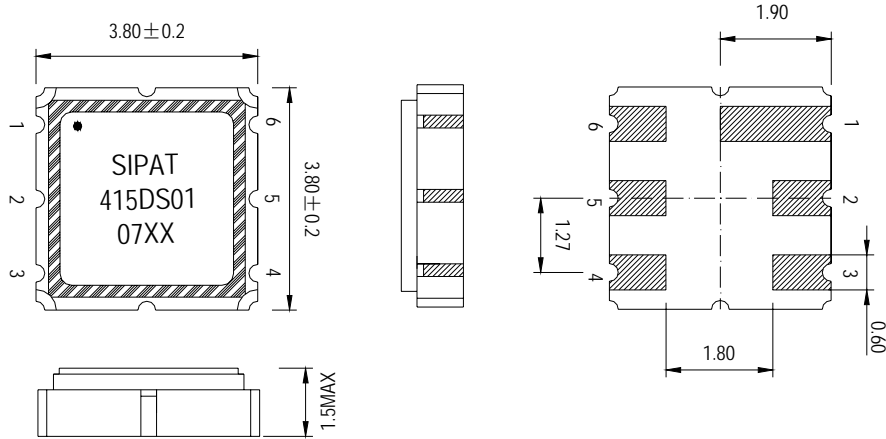


Source/Load Impedance=50 ohm

Notes - Component values may change depending on board layout.

	SIPAT Co., Ltd. (CETC No. 26 Research Institute) Nanping Huayuan Road No. 14 Chongqing, China, 400060	Part Number	LB415DS01	
		Rev. Date	2007-04-26	
		Ver.	1.0	Page

Package Dimension



- 1) ∙: Pad Number 1 Index
- 2) SIPAT: Manufacturer name
- 3) 415DS01: Part Number
- 4) 07XX: Date Code

Input	2
Output	5
Ground	1,3,4,6

Package: SMD3.8*3.8

Unit: mm

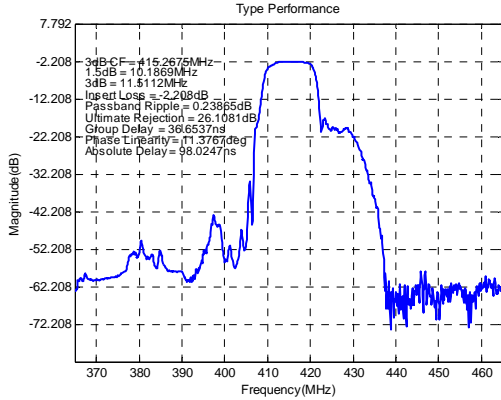


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Part Number	LB415DS01	
Rev. Date	2007-04-26	
Ver.	1.0	Page 2/4

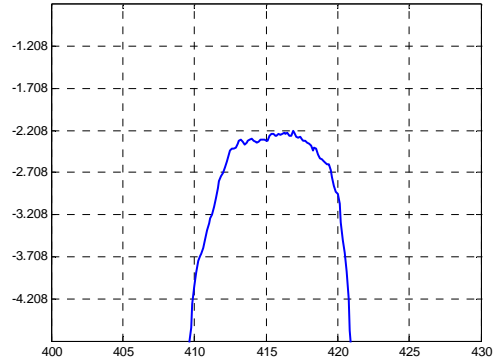
Typical Performance

Frequency Response



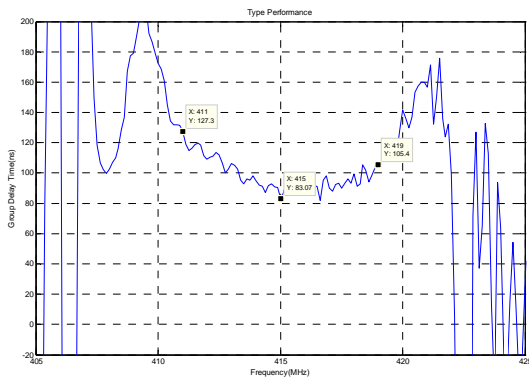
Horizontal: 10MHz/Div Vertical: 10dB/Div

Passband Response



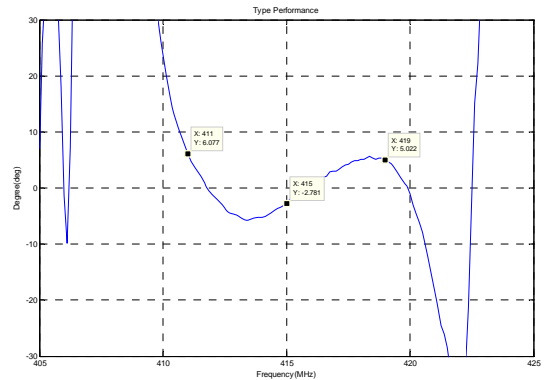
Horizontal: 5MHz/Div Vertical: 0.5dB/Div

Group Delay Variation(f0±4MHz)



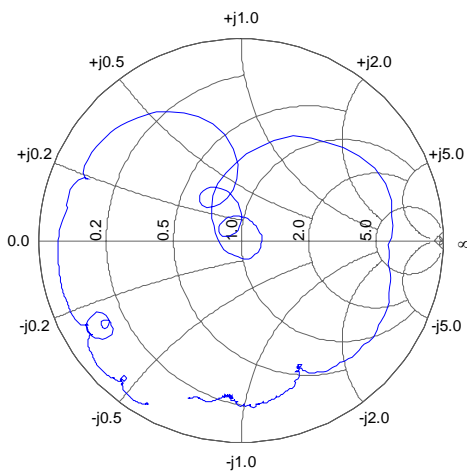
Horizontal: 5MHz/Div Vertical: 20ns/Div

Phase Linearity(f0±4MHz)

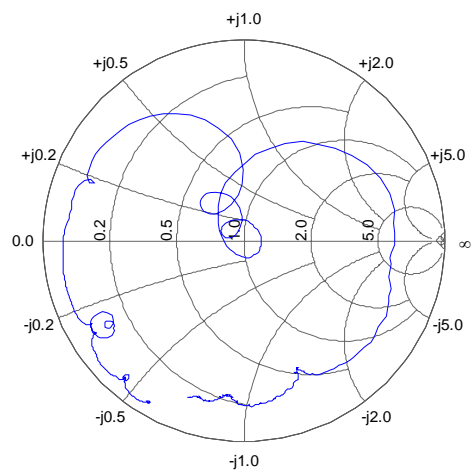


Horizontal: 5MHz/Div Vertical: 10deg/Div

Smith Chart S11



Smith Chart S22



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Ver.	1.0	Page 3/4

Maximum Ratings

Operating Temperature Range	°C	[-40°C;+85°C]
Storage Temperature Range	°C	[-40°C;+105°C]
DC Voltage	V	0
Input Power	dBm	10 max
ESD Class		1



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Ver.	1.0	Page 4/4